

12.1.2	Designs for Amorphous Silicon Solar Cells: A Guided Tour	508
12.1.3	Staebler–Wronski Effect	511
12.1.4	Synopsis of this Chapter	512
12.2	Atomic and Electronic Structure of Hydrogenated Amorphous Silicon	513
12.2.1	Atomic Structure	513
12.2.2	Defects and Metastability	514
12.2.3	Electronic Density-of-states	515
12.2.4	Bandtails, Bandedges, and Band Gaps	516
12.2.5	Defects and Gap States	517
12.2.6	Doping	518
12.2.7	Alloying and Optical Properties	518
12.3	Depositing Amorphous Silicon	520
12.3.1	Survey of Deposition Techniques	520
12.3.2	RF Glow Discharge Deposition	521
12.3.3	Glow Discharge Deposition at Different Frequencies	523
12.3.4	Hot-wire Chemical Vapor Deposition	525
12.3.5	Other Deposition Methods	526
12.3.6	Hydrogen Dilution	526
12.3.7	Alloys and Doping	528
12.4	Understanding a-Si <i>pin</i> Cells	528
12.4.1	Electronic Structure of a <i>pin</i> Device	528
12.4.2	Photocarrier Drift in Absorber Layers	530
12.4.3	Absorber Layer Design of a <i>pin</i> Solar Cell	533
12.4.4	The Open-circuit Voltage	534
12.4.5	Optical Design of a-Si:H Solar Cells	537
12.4.6	Cells under Solar Illumination	540
12.4.7	Light-soaking Effects	541
12.5	Multiple-Junction Solar Cells	542
12.5.1	Advantages of Multiple-junction Solar Cells	542
12.5.2	Using Alloys for Cells with Different Band Gaps	544
12.5.3	a-Si/a-SiGe Tandem and a-Si/a-SiGe/a-SiGe Triple-junction Solar Cells	546
12.5.4	Microcrystalline Silicon Solar Cells	551
12.5.5	Micromorph and Other μ c-Si-based Multijunction Cells	552
12.6	Module Manufacturing	553
12.6.1	Continuous Roll-to-roll Manufacturing on Stainless Steel Substrates	553
12.6.2	a-Si Module Production on Glass Superstrate	555
12.6.3	Manufacturing Cost, Safety, and Other Issues	556
12.6.4	Module Performance	557
12.7	Conclusions and Future Projections	558
12.7.1	Status and Competitiveness of a-Si Photovoltaics	558
12.7.2	Critical Issues for Further Enhancement and Future Potential	559
12.8	Acknowledgments	559
	References	560